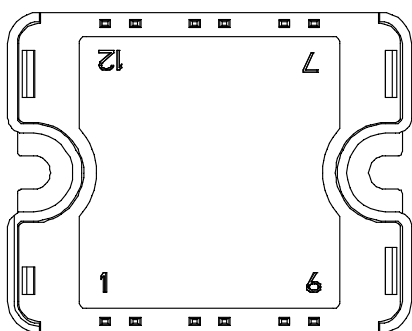
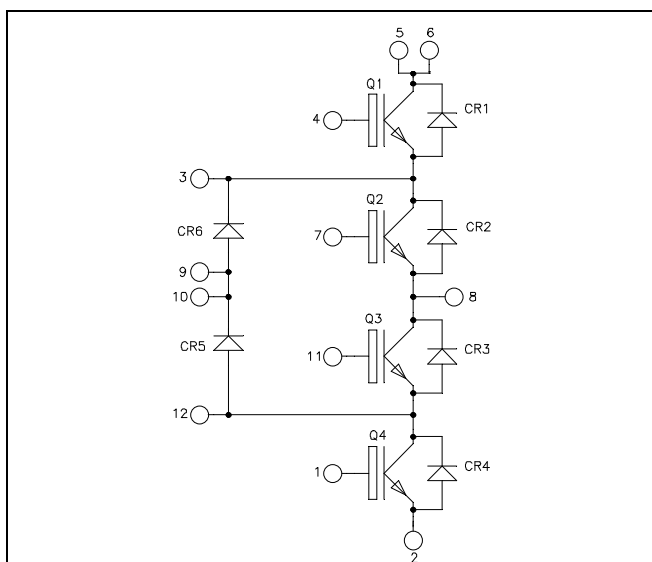


**Three level inverter  
Trench + Field Stop IGBT3  
Power Module**

**$V_{CES} = 600V$   
 $I_C = 30A @ T_c = 80^\circ C$**



All multiple inputs and outputs must be shorted together  
5/6 ; 9/10

#### Application

- Solar converter
- Uninterruptible Power Supplies

#### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Very low stray inductance
- High level of integration

#### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

#### Q1 to Q4 Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage	600	V
$I_C$	Continuous Collector Current	$T_C = 25^\circ C$	50
		$T_C = 80^\circ C$	30
$I_{CM}$	Pulsed Collector Current	$T_C = 25^\circ C$	60
$V_{GE}$	Gate - Emitter Voltage	$\pm 20$	V
$P_D$	Maximum Power Dissipation	$T_C = 25^\circ C$	90
RBSOA	Reverse Bias Safe Operating Area	$T_J = 150^\circ C$	60A @ 550V

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.  
See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

**Q1 to Q4 Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$			250	$\mu A$
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 30A$		1.5 1.7	1.9	V
		$T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$				
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 400\mu A$	5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			300	nA

**Q1 to Q4 Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{ies}$	Input Capacitance	$V_{GE} = 0V$		1600		pF
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$		110		
$C_{res}$	Reverse Transfer Capacitance	$f = 1MHz$		50		
$Q_G$	Gate charge	$V_{GE} = \pm 15V, I_C = 30A$ $V_{CE} = 300V$		0.3		$\mu C$
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $25^\circ\text{C}$ ) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_C = 30A$ $R_G = 10\Omega$		110		ns
$T_r$	Rise Time			45		
$T_{d(off)}$	Turn-off Delay Time			200		
$T_f$	Fall Time			40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $150^\circ\text{C}$ ) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_C = 30A$ $R_G = 10\Omega$		120		ns
$T_r$	Rise Time			50		
$T_{d(off)}$	Turn-off Delay Time			250		
$T_f$	Fall Time			60		
$E_{on}$	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		0.16 0.3		mJ
		$T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$				
$E_{off}$	Turn-off Switching Energy	$I_C = 30A$ $R_G = 10\Omega$		0.7 1.05		mJ
		$T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$				
$I_{sc}$	Short Circuit data	$V_{GE} \leq 15V ; V_{Bus} = 360V$ $t_p \leq 6\mu s ; T_j = 150^\circ\text{C}$		150		A
$R_{thJC}$	Junction to Case Thermal Resistance				1.6	$^\circ\text{C/W}$

**CR1 to CR4 diode ratings and characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			600			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =600V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C			150 350	μA
I <sub>F</sub>	DC Forward Current		T <sub>c</sub> = 80°C		20		A
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 20A V <sub>GE</sub> = 0V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		1.6 1.5	2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 20A V <sub>R</sub> = 300V di/dt = 1600A/μs	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		100 150		ns
Q <sub>rr</sub>	Reverse Recovery Charge		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		1.1 2.3		μC
E <sub>rr</sub>	Reverse Recovery Energy		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		0.23 0.50		mJ
R <sub>thJC</sub>	Junction to Case Thermal Resistance					3.25	°C/W

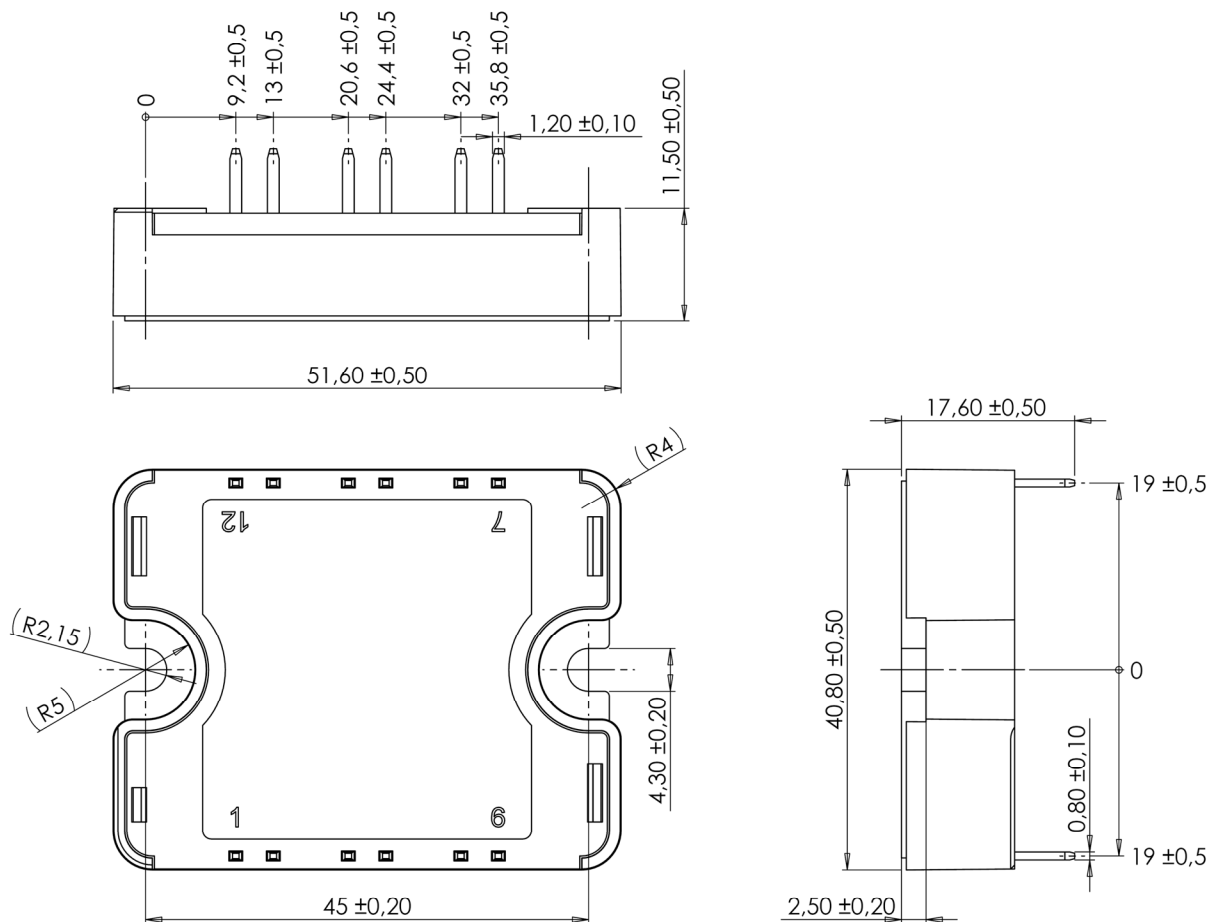
**CR5 & CR6 diode ratings and characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			600			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =600V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C			150 350	μA
I <sub>F</sub>	DC Forward Current		T <sub>c</sub> = 80°C		30		A
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 30A V <sub>GE</sub> = 0V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		1.6 1.5	2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 30A V <sub>R</sub> = 300V di/dt = 1800A/μs	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		100 150		ns
Q <sub>rr</sub>	Reverse Recovery Charge		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		1.5 3.1		μC
E <sub>rr</sub>	Reverse Recovery Energy		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		0.34 0.75		mJ
R <sub>thJC</sub>	Junction to Case Thermal Resistance					2.45	°C/W

**Thermal and package characteristics**

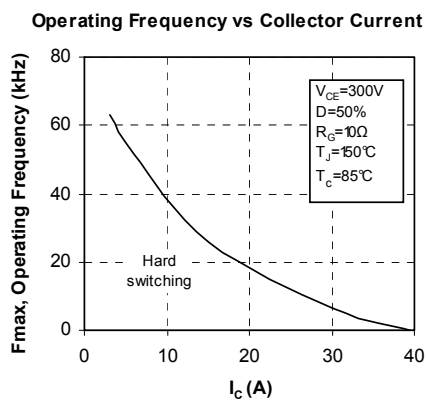
<i>Symbol</i>	<i>Characteristic</i>	<i>Min</i>		<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz	4000				V
T <sub>J</sub>	Operating junction temperature range	-40			175	°C
T <sub>STG</sub>	Storage Temperature Range	-40			125	
T <sub>C</sub>	Operating Case Temperature	-40			100	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				80	g

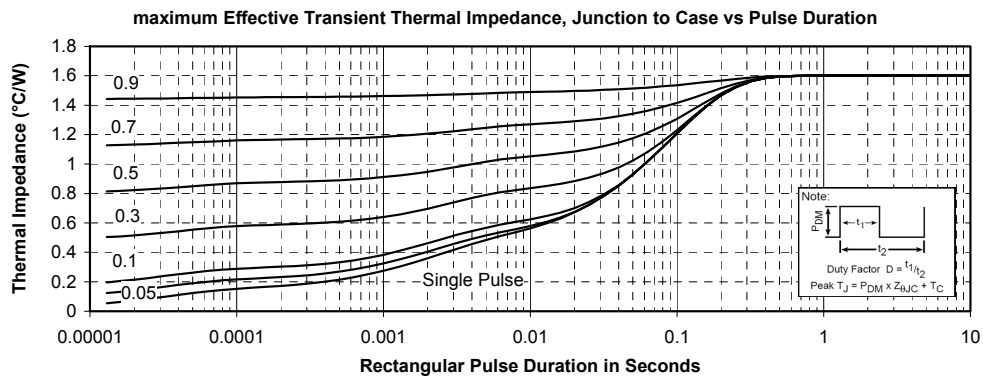
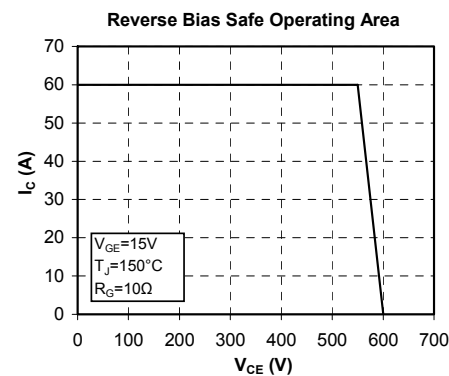
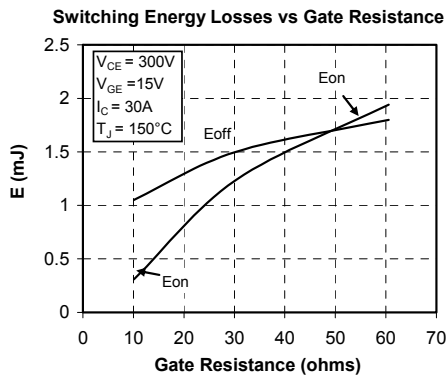
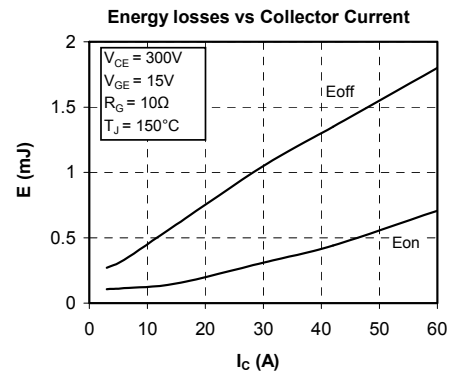
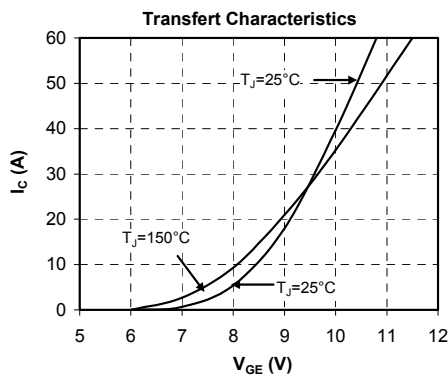
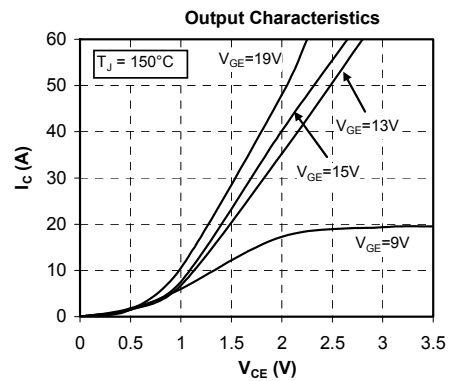
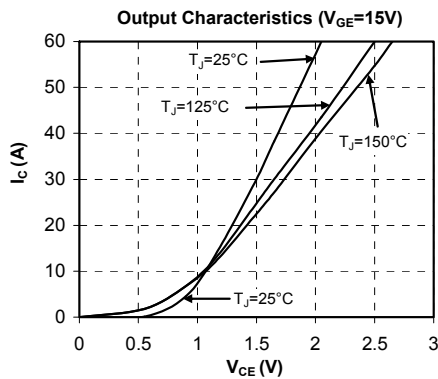
### SP1 Package outline (dimensions in mm)



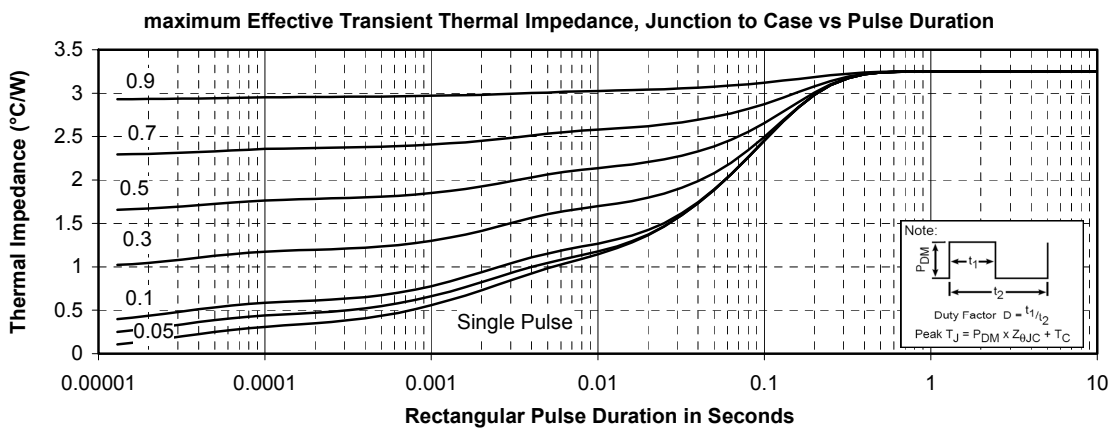
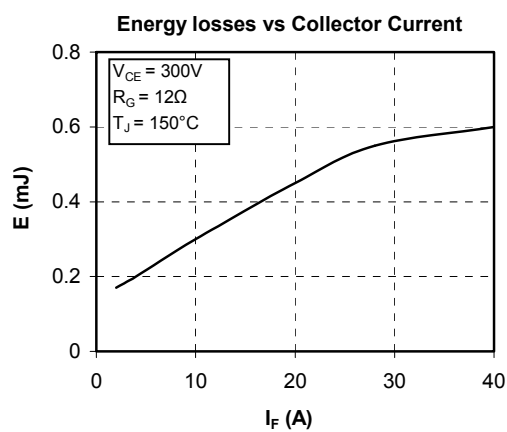
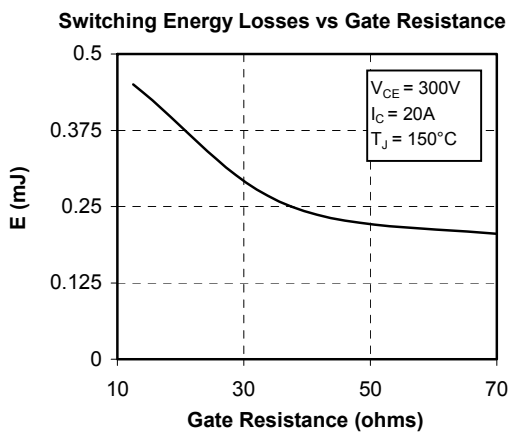
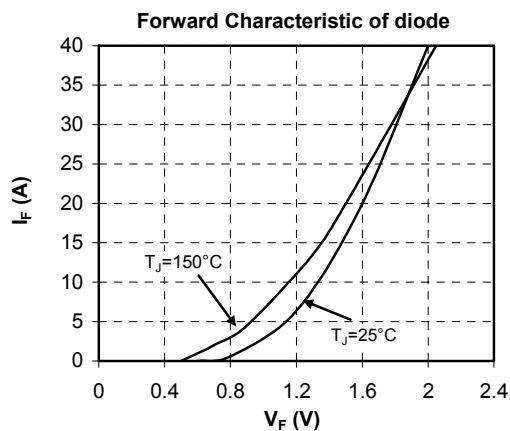
See application note 1904 - Mounting Instructions for SP1 Power Modules on [www.microsemi.com](http://www.microsemi.com)

### Q1 to Q4 Typical performance curve

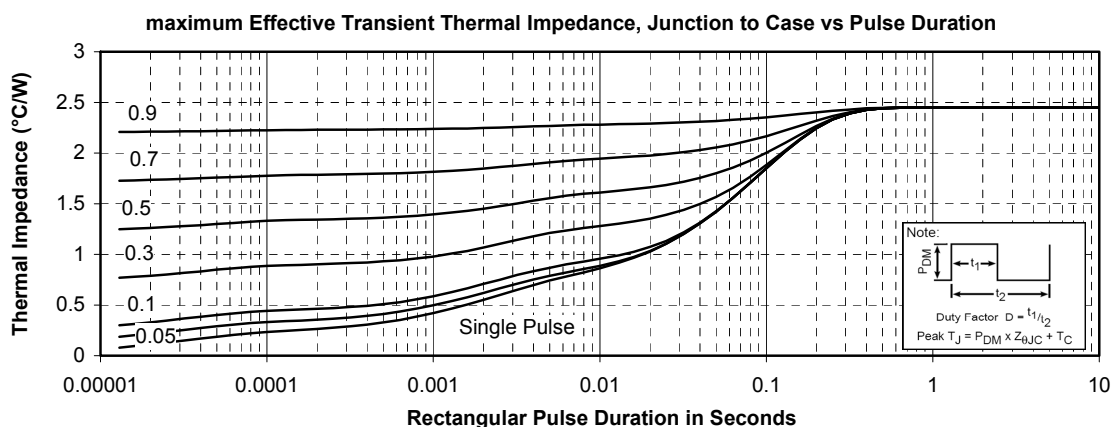
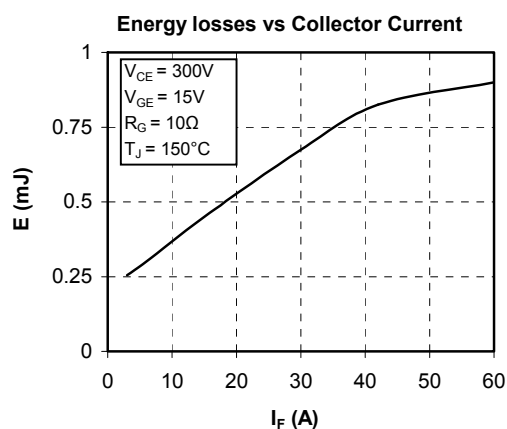
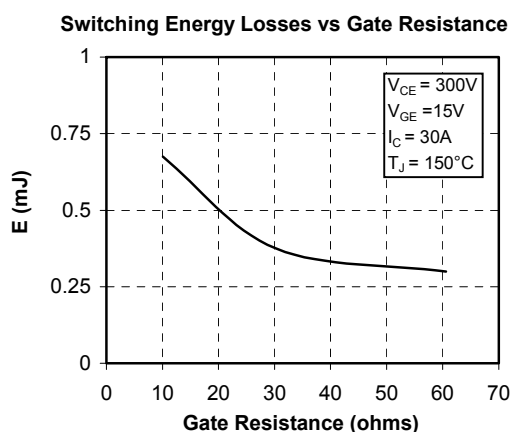
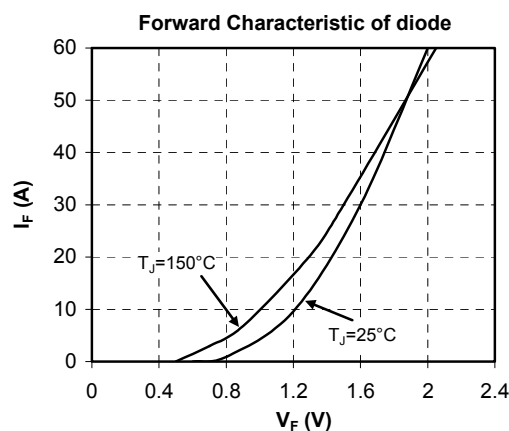




**CR1 to CR4 Typical performance curve**



## CR5 & CR6 Typical performance curve



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